L Number	Hits	Search Text	DB	Time stamp
-	4200	(438/17,18,11,for.101,for.102,for.142).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 11:14
-	4	((438/17,18,11,for.101,for.102,for.142).CCLS.) and LOCOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 13:54
-	36	((438/17,18,11,for.101,for.102,for.142).CCLS.) and field near2 (oxidat$4 oxydat$4 insulat$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 14:29
-	18	((438/17,18,11,for.101,for.102,for.142).CCLS.) and fox not (((438/17,18,11,for.101,for.102,for.142).CCLS.) and field near2 (oxidat$4 oxydat$4 insulat$4))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 14:13
-	0	(Etching etched etch) near2 substrate with (fox locos field near (oxide oxidation oxyde oxydation)) near2 mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 09:43
-	36	(Etching etched etch) near2 substrate with (fox locos field near (oxide oxidation oxyde oxydation)) near2 mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 15:06
-	5	5652458.URPN.	USPAT	2003/08/27 15:00
-	1	"5200351".PN.	USPAT	2003/08/27 15:00
-	6	5563080.URPN.	USPAT	2003/08/27 15:00
-	5	("3861024" | "3958040" | "3980508" | "4242156" | "4313256" | "4667395" | "5132238" | "5200351").PN.	USPAT	2003/08/27 15:00
-	17	(5652458.URPN. "5200351".PN. 5563080.URPN. (("3861024" | "3958040" | "3980508" | "4242156" | "4313256" | "4667395" | "5132238" | "5200351").PN.)) not ((Etching etched etch) near2 substrate with (fox locos field near (oxide oxidation oxyde oxydation)) near2 mask)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 15:00
-	42	(Etching etched etch) near2 (silicon si) with (fox locos field near (oxide oxidation oxyde oxydation)) near2 mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 15:07
-	29	((Etching etched etch) near2 (silicon si) with (fox locos field near (oxide oxidation oxyde oxydation)) near2 mask) not ((Etching etched etch) near2 substrate with (fox locos field near (oxide oxidation oxyde oxydation)) near2 mask)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 15:07
-	8	("4639893" | "4990979" | "5021999" | "5095344" | "5723888" | "5812449" | "5851881" | "6190968").PN.	USPAT	2003/08/27 15:58
-	0	6566707.URPN.	USPAT	2003/08/27 15:59
-	4200	(438/17,18,11,for.101,for.102,for.142).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 16:02

-	0	(n and p) near3 (substrate silicon si) and ((438/17,18,11,for.101,for.102,for.142).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 16:03
-	40	(n and p) near4 (substrate silicon si) and ((438/17,18,11,for.101,for.102,for.142).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 16:08
-	83	(n and p) near2 (substrate silicon si) and ((438/17,18,11,for.101,for.102,for.142).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 16:08
-	144	(n and p) near4 (substrate silicon si) and ((438/17,18,11,for.101,for.102,for.142).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 16:25
-	1	electron near charge near effect	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 17:00
-	2	("6143579").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 17:01
-	0	breakdown near voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 17:01
-	4	braekdown near voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 17:01
-	42057	breakdown near voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 17:02
-	7870	breakdown near voltage with current	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 17:03
-	1168	breakdown near voltage with current with gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 17:03
-	125	breakdown near voltage with current with gate with substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 17:20

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-	346	dry adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 17:21
-	186	dry adj oxide and (438/$6 257/$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/27 17:21
-	9197	(square rectangle) with (poly si polysilicon silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 09:41
-	4201	(438/17,18,11,for.101,for.102,for.142).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 09:34
-	38	((square rectangle) with (poly si polysilicon silicon)) and ((438/17,18,11,for.101,for.102,for.142).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 09:38
-	2346	((square rectangle) with (poly si polysilicon silicon)) and (438/$6 257/$6) and (sens$3 detect$3 measur$3 test$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 09:42
-	1013	((square rectangle) with (poly si polysilicon silicon)) and (438/$6 257/$6) and (sens$3 detect$3 measur$3 test$3) with (poly si polysilicon silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 09:42
-	755	(((square rectangle) with (poly si polysilicon silicon)) and (438/$6 257/$6) and (sens$3 detect$3 measur$3 test$3) with (poly si polysilicon silicon)) and (poly si polysilicon silicon) with (pad area pattern)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 09:42
-	585	(((square rectangle) with (poly si polysilicon silicon)) and (438/$6 257/$6) and (sens$3 detect$3 measur$3 test$3)) and (fox locos field near (oxide oxidation oxyde oxydation))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 09:43
-	124	((((square rectangle) with (poly si polysilicon silicon)) and (438/$6 257/$6) and (sens$3 detect$3 measur$3 test$3)) and (fox locos field near (oxide oxidation oxyde oxydation))) and (fox locos field near (oxide oxidation oxyde oxydation)) same (square rectangle)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 10:26
-	124	((((square rectangle) with (poly si polysilicon silicon)) and (438/$6 257/$6) and (sens$3 detect$3 measur$3 test$3)) and (fox locos field near (oxide oxidation oxyde oxydation))) and (fox locos field near (oxide oxidation oxyde oxydation)) same (square rectangle)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 10:29

-	51	((((square rectangle) with (poly si polysilicon silicon)) and (438/$6 257/$6) and (sens$3 detect$3 measur$3 test$3)) and (fox locos field near (oxide oxidation oxyde oxydation))) and (fox locos field near (oxide oxidation oxyde oxydation)) same (array) not (((((square rectangle) with (poly si polysilicon silicon)) and (438/$6 257/$6) and (sens$3 detect$3 measur$3 test$3)) and (fox locos field near (oxide oxidation oxyde oxydation))) and (fox locos field near (oxide oxidation oxyde oxydation)) same (square rectangle))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 10:49
-	4	monitor$3 with recycl$3 with anneal$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 10:50
-	4201	(438/17,18,11,for.101,for.102,for.142).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 11:14
-	3	((438/17,18,11,for.101,for.102,for.142).CCLS.) and (fox locos field near (oxide oxidation oxyde oxydation)) near2 mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 11:15
-	121	((438/17,18,11,for.101,for.102,for.142).CCLS.) and (fox locos field near (oxide oxidation oxyde oxydation))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/28 11:16